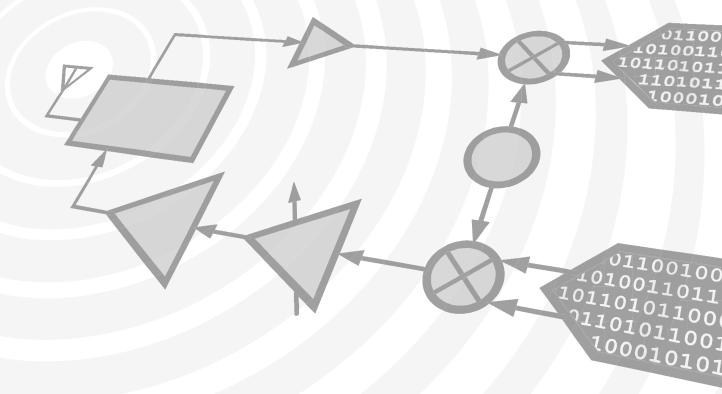




Analog Devices Welcomes Hittite Microwave Corporation



www.hittite.com

www.analog.com

HMC441LC3B* Product Page Quick Links

Last Content Update: 11/01/2016

Comparable Parts

View a parametric search of comparable parts

Evaluation Kits

• HMC441LC3B Evaluation Board

Documentation 🖵

Application Notes

- AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers
- Broadband Biasing of Amplifiers General Application Note
- MMIC Amplifier Biasing Procedure Application Note
- Thermal Management for Surface Mount Components General Application Note

Data Sheet

• HMC441LC3B Data Sheet

Tools and Simulations

• HMC441LC3B S-Parameters

Reference Materials

Quality Documentation

- Package/Assembly Qualification Test Report: LC3, LC3B, LC3C (QTR: 2014-00376 REV: 01)
- Semiconductor Qualification Test Report: PHEMT-F (QTR: 2013-00269)

Design Resources

- HMC441LC3B Material Declaration
- PCN-PDN Information
- Quality And Reliability
- · Symbols and Footprints

Discussions 🖵

View all HMC441LC3B EngineerZone Discussions

Sample and Buy

Visit the product page to see pricing options

Technical Support

Submit a technical question or find your regional support number

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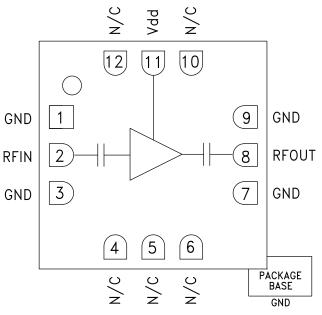


Typical Applications

The HMC441LC3B is ideal for use as a medium power amplifier for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- LO Driver for HMC Mixers
- Military EW & ECM

Functional Diagram



HMC441LC3B

v07.0615

GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 6 - 18 GHz

Features

Gain: 14 dB Saturated Output Power: +21.5 dBm @ 27% PAE Single Positive Supply: +5V @ 90 mA 50 Ohm Matched Input/Output 12 Lead Ceramic 3x3mm SMT Package: 9mm²

General Description

The HMC441LC3B is an efficient GaAs PHEMT MMIC Medium Power Amplifier housed in a leadless RoHS compliant SMT package. Operating between 6 and 18 GHz, the amplifier provides 14 dB of gain, +21.5 dBm of saturated power and 27% PAE from a +5V supply. This 50 Ohm matched amplifier does not require any external components and operates from a single positive supply, making it an ideal linear gain block or driver for HMC SMT mixers. The HMC441LC3B is compatible with high volume surface mount manufacturing techniques, and the I/Os are DC blocked for further ease of integration.

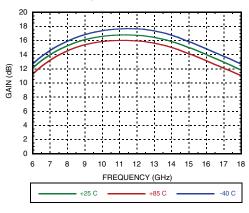
Electrical Specifications, $T_{a} = +25^{\circ} C$, Vdd = +5V

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	6.0 - 8.5		8.5 - 12.5		12.5 - 14.0		14.0 - 18.0		GHz				
Gain	10	14	19	13	17	21	13	17	21	10	14	19	dB
Gain Variation Over Temperature		0.015	0.02		0.015	0.02		0.015	0.02		0.015	0.02	dB/ °C
Input Return Loss		10			13			20			13		dB
Output Return Loss		12			15			17			14		dB
Output Power for 1 dB Compression (P1dB)	16	19		17	20		17	20		17	20		dBm
Saturated Output Power (Psat)		20			21.5			22.5			21.5		dBm
Output Third Order Intercept (IP3)	28	30		29	32		29	32		29	32		dBm
Noise Figure		4.5	6		4.5	6		4.5	6		4.5	6	dB
Supply Current (Idd)		90	115		90	115		90	115		90	115	mA

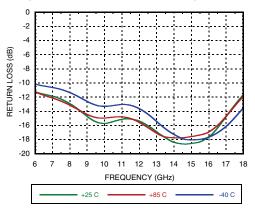
For price, delivery and to place orders: Hittite Microwave Corporation, 2 Elizabeth Drive, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com Application Support: Phone: 978-250-3343 or apps@hittite.com

GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 6 - 18 GHz

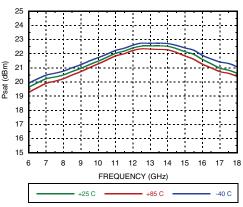
Gain vs. Temperature



Output Return Loss vs. Temperature

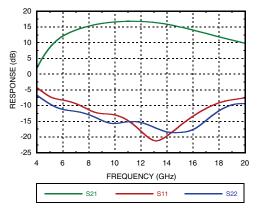




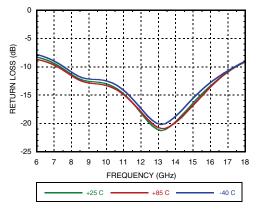




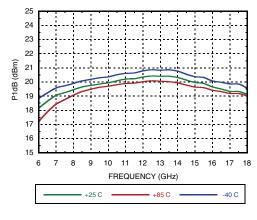
Broadband Gain & Return Loss



Input Return Loss vs. Temperature



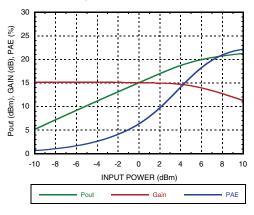
P1dB vs. Temperature

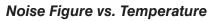


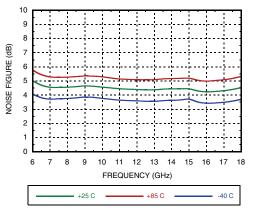
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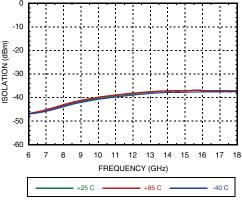


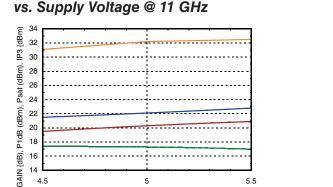






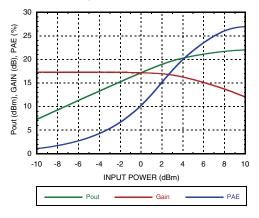
Reverse Isolation vs. Temperature



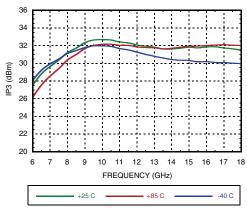


Vdd (V)

Power Compression @ 11 GHz



Output IP3 vs. Temperature



Gain, Power & Output IP3 vs. Supply Voltage @ 11 GHz

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GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 6 - 18 GHz

Typical Supply Current vs. Vdd

Vdd (V)	ldd (mA)
+5.5	92
+5.0	90
+4.5	88

Note: Amplifier will operate over full voltage range shown above



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing

FROM ANALOG DEVICES

Drain Bias Voltage (Vdd)

Channel Temperature Continuous Pdiss (T = 85 °C)

Thermal Resistance

(channel to ground paddle) Storage Temperature

Operating Temperature

ESD Sensitivity (HBM)

Absolute Maximum Ratings

RF Input Power (RFIN)(Vdd = +5 Vdc)

(derate 8.2 mW/°C above 85 °C)

+6 Vdc

+15 dBm

175 °C

0.74 W

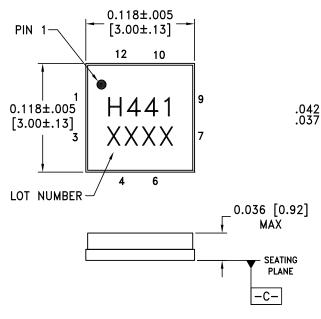
122 °C/W

-65 to +150 °C

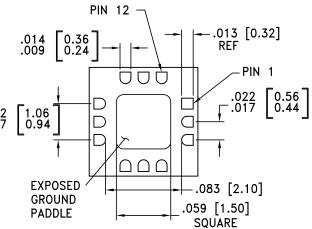
-40 to +85 °C

Class 0, Passed 125V

RoHSv



BOTTOM VIEW



NOTES:

1. PACKAGE BODY MATERIAL: ALUMINA

- 2. LEAD AND GROUND PADDLE PLATING: GOLD FLASH OVER Ni.
- 3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE

5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.

6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

[Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]	
	HMC441LC3B	Alumina, White	Gold over Nickel	MSL3 ^[1]	H441 XXXX	

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX



HMC441LC3B v07.0615

GaAs pHEMT MMIC MEDIUM **POWER AMPLIFIER, 6 - 18 GHz**



Pin Descriptions

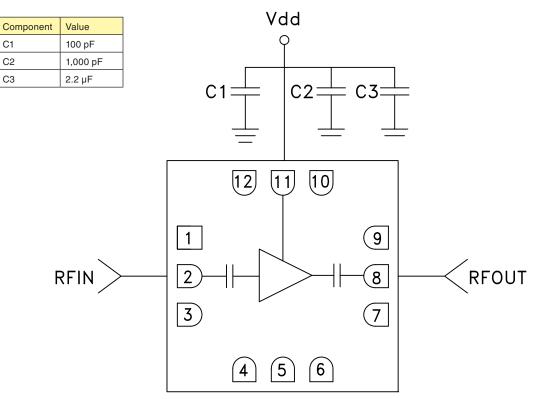
Pin Number	Function	Description	Interface Schematic
1, 3, 7, 9	GND	Package bottom must also be connected to RF/DC ground	
2	RFIN	This pin is AC coupled and matched to 50 Ohms.	
4 - 6 10, 12	N/C	This pin may be connected to RF/DC ground. Performance will not be affected.	
8	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
11	Vdd	Power Supply Voltage for the amplifier. External bypass capacitors are required.	OVdd ↓ ↓ ↓ ↓ ↓ ↓

Application Circuit

C1

C2

СЗ



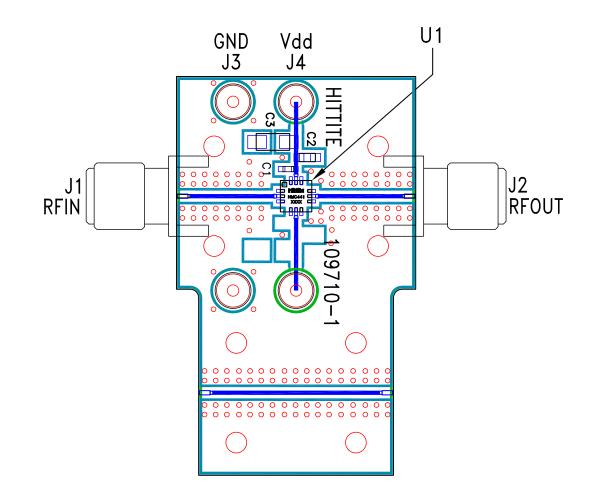
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HMC441LC3B

GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 6 - 18 GHz



Evaluation PCB



List of Materials for Evaluation PCB 109712 [1]

Item	Description	
J1 - J2	PCB Mount SMA Connector	
J3 - J4	DC Pin	
C1	100 pF Capacitor, 0402 Pkg.	
C2	1000 pF Capacitor, 0603 Pkg.	
C3	2.2 µF Capacitor, Tantalum	
U1	HMC441LC3B Amplifier	
PCB [2]	109710 Evaluation PCB, 10 mils	

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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